

NCP3420

MOSFET Driver with Dual Outputs for Synchronous Buck Converters

The NCP3420 is a single Phase 12 V MOSFET gate driver optimized to drive the gates of both high-side and low-side power MOSFETs in a synchronous buck converter. The high-side and low-side driver is capable of driving a 3000 pF load with a 30 ns propagation delay and a 20 ns transition time.

With a wide operating voltage range, high or low side MOSFET gate drive voltage can be optimized for the best efficiency. Internal adaptive nonoverlap circuitry further reduces switching losses by preventing simultaneous conduction of both MOSFETs.

The floating top driver design can accommodate VBST voltages as high as 35 V, with transient voltages as high as 40 V. Both gate outputs can be driven low by applying a low logic level to the Output Disable (OD) pin. An Undervoltage Lockout function ensures that both driver outputs are low when the supply voltage is low, and a Thermal Shutdown function provides the IC with overtemperature protection.

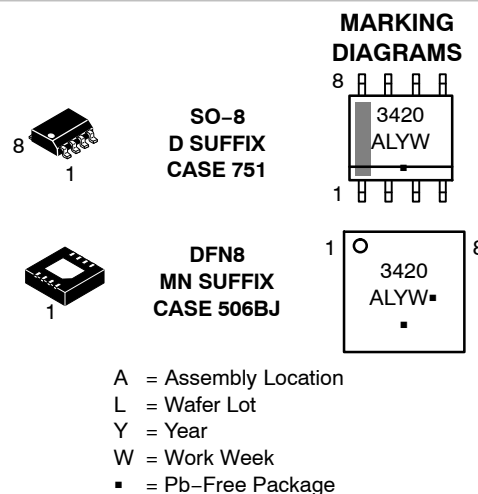
Features

- Thermal Shutdown for System Protection
- Internal Pulldown Resistor Suppresses Transient Turn On of Either MOSFET
- Anti Cross-Conduction Protection Circuitry
- One Input Signal Controls Both the Upper and Lower Gate Outputs
- Output Disable Control Turns Off Both MOSFETs
- Complies with VRM10.x and VRM11.x Specifications
- Undervoltage Lockout
- Thermally Enhanced Package Available
- These are Pb-Free Devices

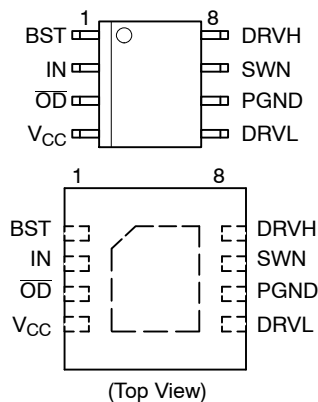


ON Semiconductor®

<http://onsemi.com>



PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping†
NCP3420DR2G	SO-8 (Pb-Free)	2500 Tape & Reel
NCP3420MNR2G	DFN8 (Pb-Free)	3000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NCP3420

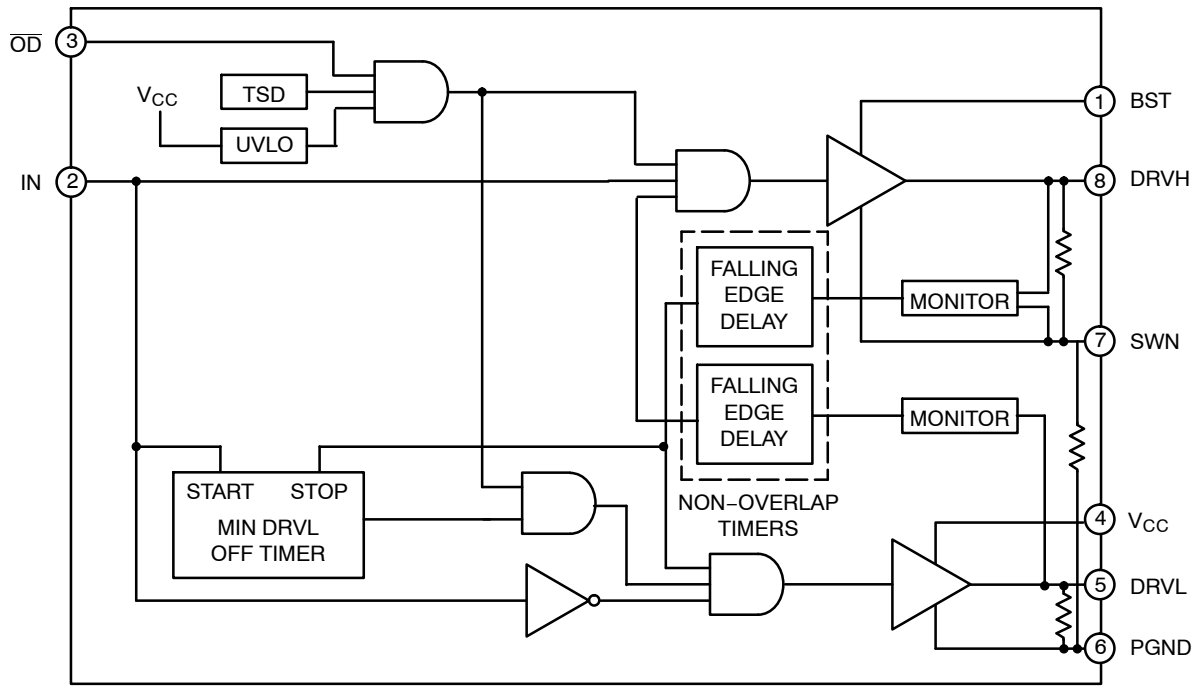


Figure 1. Block Diagram

PIN DESCRIPTION

SO-8	DFN8	Symbol	Description
1	1	BST	Upper MOSFET Floating Bootstrap Supply. A capacitor connected between BST and SW pins holds this bootstrap voltage for the high-side MOSFET as it is switched. The recommended capacitor value is between 100 nF and 1.0 μ F. An external diode is required with the NCP3420.
2	2	IN	Logic-Level Input. This pin has primary control of the drive outputs.
3	3	$\overline{\text{OD}}$	Output Disable. When low, normal operation is disabled forcing DRVH and DRVL low.
4	4	VCC	Input Supply. A 1.0 μ F ceramic capacitor should be connected from this pin to PGND.
5	5	DRVL	Output drive for the lower MOSFET.
6	6	PGND	Power Ground. Should be closely connected to the source of the lower MOSFET.
7	7	SWN	Switch Node. Connect to the source of the upper MOSFET.
8	8	DRVH	Output drive for the upper MOSFET.

NCP3420

MAXIMUM RATINGS

Rating	Value	Unit
Operating Ambient Temperature, T_A	0 to 85	$^{\circ}\text{C}$
Operating Junction Temperature, T_J (Note 1)	0 to 150	$^{\circ}\text{C}$
Package Thermal Resistance: SO-8 Junction-to-Case, $R_{\theta JC}$ Junction-to-Ambient, $R_{\theta JA}$ (2-Layer Board)	45 123	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
Package Thermal Resistance: DFN8 (Note 2) Junction-to-Case, $R_{\theta JC}$ (From die to exposed pad) Junction-to-Ambient, $R_{\theta JA}$	7.5 55	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
Storage Temperature Range, T_S	-65 to 150	$^{\circ}\text{C}$
Lead Temperature Soldering (10 sec): Reflow (SMD styles only) Pb-Free (Note 3)	260 peak	$^{\circ}\text{C}$
JEDEC Moisture Sensitivity Level SO-8 (260 peak profile)	1	-

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Internally limited by thermal shutdown, 150 $^{\circ}\text{C}$ min.
2. 2 layer board, 1 in² Cu, 1 oz thickness.
3. 60–180 seconds minimum above 237 $^{\circ}\text{C}$.

NOTE: This device is ESD sensitive. Use standard ESD precautions when handling.

MAXIMUM RATINGS

Pin Symbol	Pin Name	V_{MAX}	V_{MIN}
V_{CC}	Main Supply Voltage Input	15 V	-0.3 V
PGND	Ground	0 V	0 V
BST	Bootstrap Supply Voltage Input	35 V wrt/PGND 40 V $\leq$ 50 ns wrt/PGND 15 V wrt/SW	-0.3 V wrt/SW
SW	Switching Node (Bootstrap Supply Return)	35 V DC 40 V < 50 ns	-5.0 V DC -10 V < 200 ns
DRVH	High-Side Driver Output	BST + 0.3 V 35 V $\leq$ 50 ns wrt/PGND 15 V wrt/SW	-0.3 V wrt/SW -2.0 V < 200 ns wrt/SW
DRVL	Low-Side Driver Output	$V_{CC} + 0.3$ V	-0.3 V DC -5.0 V < 200 ns
IN	DRVH and DRVL Control Input	6.5 V	-0.3 V
$\overline{OD}$	Output Disable	6.5 V	-0.3 V

NOTE: All voltages are with respect to PGND except where noted.

NCP3420

ELECTRICAL CHARACTERISTICS (Note 4) ($V_{CC} = 12\text{ V}$, $T_A = 0^\circ\text{C}$ to $+85^\circ\text{C}$, $T_J = 0^\circ\text{C}$ to $+125^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Condition	Min	Typ	Max	Unit
----------------	--------	-----------	-----	-----	-----	------

Supply

Supply Voltage Range	V_{CC}	–	4.6	–	13.2	V
Supply Current	I_{SYS}	BST = 12 V, IN = 0 V	–	0.7	6.0	mA

OD Input

Input Voltage High	$\overline{V_{OD_HI}}$	–	2.0	–	–	V
Input Voltage Low	$\overline{V_{OD_LO}}$	–	–	–	0.8	V
Hysteresis	–	–	–	400	–	mV
Input Current	–	No internal pull-up or pull-down resistors	–1.0	–	+1.0	μA
Propagation Delay Time	$\overline{t_{pdlOD}}$ $\overline{t_{pdhOD}}$	–	1.0 1.0	25 25	45 45	ns ns

PWM Input

Input Voltage High	V_{PWM_HI}	–	2.0	–	–	V
Input Voltage Low	V_{PWM_LO}	–	–	–	0.8	V
Hysteresis	–	–	–	500	–	mV
Input Current	–	No internal pull-up or pull-down resistors	–1.0	–	+1.0	μA

High-Side Driver

Output Resistance, Sourcing Current	–	$V_{BST} - V_{SW} = 12\text{ V}$ (Note 6)	–	1.8	3.0	Ω
Output Resistance, Sinking Current	–	$V_{BST} - V_{SW} = 12\text{ V}$ (Note 6)	–	1.0	2.5	Ω
SW Pulldown Resistance	–	SW to PGND	10	–	55	k Ω
Output Resistance, Unbiased	–	BST–SW = 0 V	10	–	55	k Ω
Transition Times	t_{rDRVH} t_{fDRVH}	$V_{BST} - V_{SW} = 12\text{ V}$, $C_{LOAD} = 3.0\text{ nF}$ (See Figure 3)	– –	16 11	30 25	ns ns
Propagation Delay (Note 5)	$t_{pdhDRVH}$ $t_{pdlDRVH}$	$V_{BST} - V_{SW} = 12\text{ V}$, $C_{LOAD} = 3.0\text{ nF}$ (See Figure 3)	20 10	30 30	45 45	ns ns

Low-Side Driver

Output Resistance, Sourcing Current	–	$V_{CC} = 12\text{ V}$ (Note 6)	–	1.8	3.0	Ω
Output Resistance, Sinking Current	–	$V_{CC} - \text{PGND} = 12\text{ V}$ (Note 6)	–	1.0	2.5	Ω
Output Resistance, Unbiased	–	$V_{CC} = \text{PGND}$	10	–	55	k Ω
Timeout Delay	–	DRVH–SW = 0	–	85	–	ns
Transition Times	t_{rDRVL} t_{fDRVL}	$V_{BST} - V_{SW} = 12\text{ V}$, $C_{LOAD} = 3.0\text{ nF}$ (See Figure 3)	– –	16 11	30 25	ns ns
Propagation Delay (Note 5)	$t_{pdhDRVL}$ $t_{pdlDRVL}$	$V_{BST} - V_{SW} = 12\text{ V}$, $C_{LOAD} = 3.0\text{ nF}$ (Note 6, $t_{pdhDRVL}$ Only) (See Figure 3)	15 10	30 30	45 45	ns ns

Undervoltage Lockout

UVLO Startup	–	–	3.9	4.3	4.5	V
UVLO Shutdown	–	–	3.7	4.1	4.3	V
Hysteresis	–	–	0.1	0.2	0.4	V

Thermal Shutdown

Over Temperature Protection	–	(Note 6)	150	170	–	$^\circ\text{C}$
Hysteresis	–	(Note 6)	–	20	–	$^\circ\text{C}$

4. All limits at temperature extremes are guaranteed via correlation using standard Statistical Quality Control (SQC).

5. For propagation delays, “ t_{pdh} ” refers to the specified signal going high; “ t_{pdl} ” refers to it going low.

6. GBD: Guaranteed by design; not tested in production.

Specifications subject to change without notice.

NCP3420

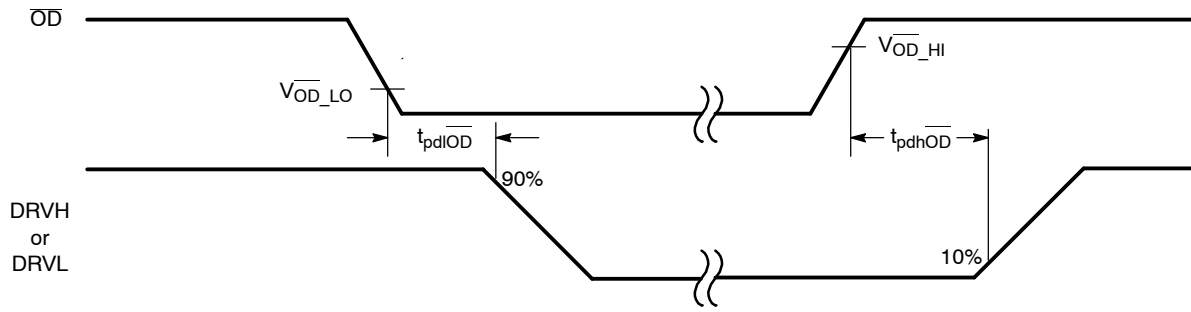


Figure 2. Output Disable Timing Diagram

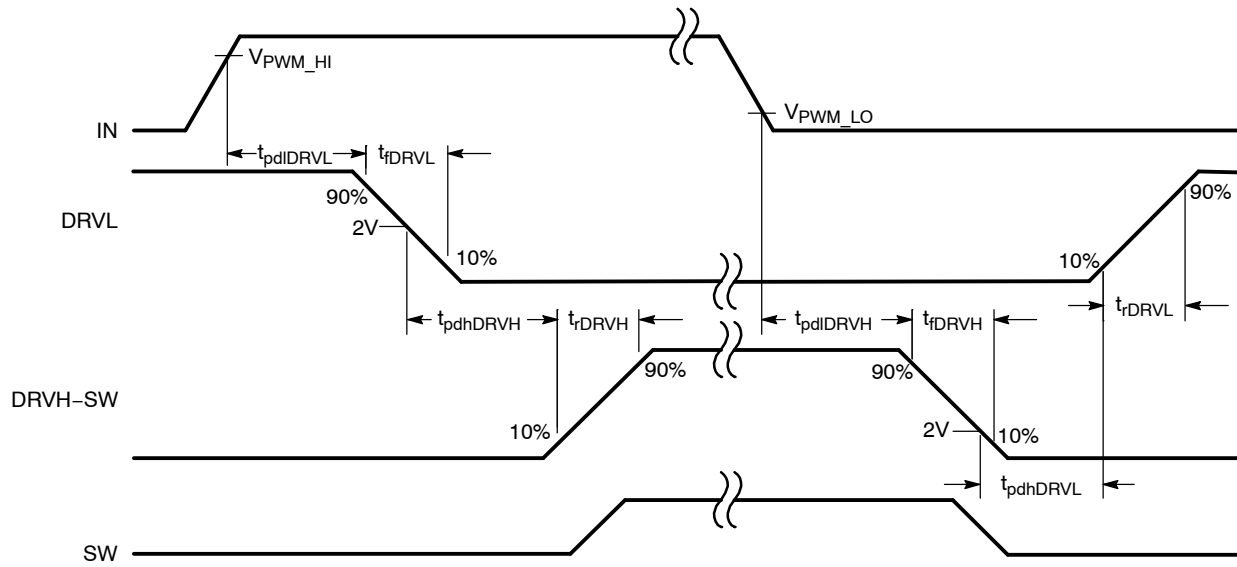


Figure 3. Nonoverlap Timing Diagram

APPLICATIONS INFORMATION

Theory of Operation

The NCP3420 are single phase MOSFET drivers designed for driving two N-channel MOSFETs in a synchronous buck converter topology. The NCP3420 will operate from 5 V or 12 V, but have been optimized for high current multi-phase buck regulators that convert 12 V rail directly to the core voltage required by complex logic chips. A single PWM input signal is all that is required to properly drive the high-side and the low-side MOSFETs. Each driver is capable of driving a 3.3 nF load at frequencies up to 1 MHz.

Low-Side Driver

The low-side driver is designed to drive a ground-referenced low $R_{DS(on)}$ N-Channel MOSFET. The voltage rail for the low-side driver is internally connected to the VCC supply and PGND.

High-Side Driver

The high-side driver is designed to drive a floating low $R_{DS(on)}$ N-channel MOSFET. The gate voltage for the high side driver is developed by a bootstrap circuit referenced to Switch Node (SW) pin.

The bootstrap circuit is comprised of an external diode, and an external bootstrap capacitor. When the NCP3420 are starting up, the SW pin is at ground, so the bootstrap capacitor will charge up to VCC through the bootstrap diode. See Figure 4. When the PWM input goes high, the high-side driver will begin to turn on the high-side MOSFET using the stored charge of the bootstrap capacitor. As the high-side MOSFET turns on, the SW pin will rise. When the high-side MOSFET is fully on, the switch node will be at 12 V, and the BST pin will be at 12 V plus the charge of the bootstrap capacitor (approaching 24 V).

The bootstrap capacitor is recharged when the switch node goes low during the next cycle.

Safety Timer and Overlap Protection Circuit

It is very important that MOSFETs in a synchronous buck regulator do not both conduct at the same time. Excessive shoot-through or cross conduction can damage the MOSFETs, and even a small amount of cross conduction will cause a decrease in the power conversion efficiency.

The NCP3420 prevent cross conduction by monitoring the status of the external mosfets and applying the appropriate amount of “dead-time” or the time between the turn off of one MOSFET and the turn on of the other MOSFET.

When the PWM input pin goes high, DRVH will go low after a propagation delay ($t_{pd}DRVH$). The time it takes for the low-side MOSFET to turn off ($t_{f}DRVH$) is dependent on the total charge on the low-side MOSFET gate. The NCP3420 monitor the gate voltage of both MOSFETs and the switchnode voltage to determine the conduction status of the MOSFETs. Once the low-side MOSFET is turned off an internal timer will delay ($t_{pd}DRVH$) the turn on of the high-side MOSFET

Likewise, when the PWM input pin goes low, DRVH will go low after the propagation delay ($t_{pd}DRVH$). The time to turn off the high-side MOSFET ($t_{f}DRVH$) is dependent on the total gate charge of the high-side MOSFET. A timer will be triggered once the high-side mosfet has stopped conducting, to delay ($t_{pd}DRVH$) the turn on of the low-side MOSFET

Power Supply Decoupling

The NCP3420 can source and sink relatively large currents to the gate pins of the external MOSFETs. In order to maintain a constant and stable supply voltage (V_{CC}) a low ESR capacitor should be placed near the power and ground pins. A 1 μ F to 4.7 μ F multi layer ceramic capacitor (MLCC) is usually sufficient.

Input Pins

The PWM input and the Output Disable pins of the NCP3420 have internal protection for Electro Static Discharge (ESD), but in normal operation they present a relatively high input impedance. If the PWM controller does not have internal pull-down resistors, they should be added externally to ensure that the driver outputs do not go high before the controller has reached its under voltage lockout threshold. The NCP5381 controller does include a passive internal pull-down resistor on the drive-on output pin.

Bootstrap Circuit

The bootstrap circuit uses a charge storage capacitor (C_{BST}) and the internal (or an external) diode. Selection of these components can be done after the high-side MOSFET has been chosen. The bootstrap capacitor must have a voltage rating that is able to withstand twice the maximum supply voltage. A minimum 50 V rating is recommended. The capacitance is determined using the following equation:

$$C_{BST} = \frac{Q_{GATE}}{\Delta V_{BST}}$$

where Q_{GATE} is the total gate charge of the high-side MOSFET, and ΔV_{BST} is the voltage droop allowed on the high-side MOSFET drive. For example, a NTD60N03 has a total gate charge of about 30 nC. For an allowed droop of 300 mV, the required bootstrap capacitance is 100 nF. A good quality ceramic capacitor should be used.

The bootstrap diode must be rated to withstand the maximum supply voltage plus any peak ringing voltages that may be present on SW. The average forward current can be estimated by:

$$I_F(AVG) = Q_{GATE} \times f_{MAX}$$

where f_{MAX} is the maximum switching frequency of the controller. The peak surge current rating should be checked in-circuit, since this is dependent on the source impedance of the 12 V supply and the ESR of C_{BST} .

NCP3420

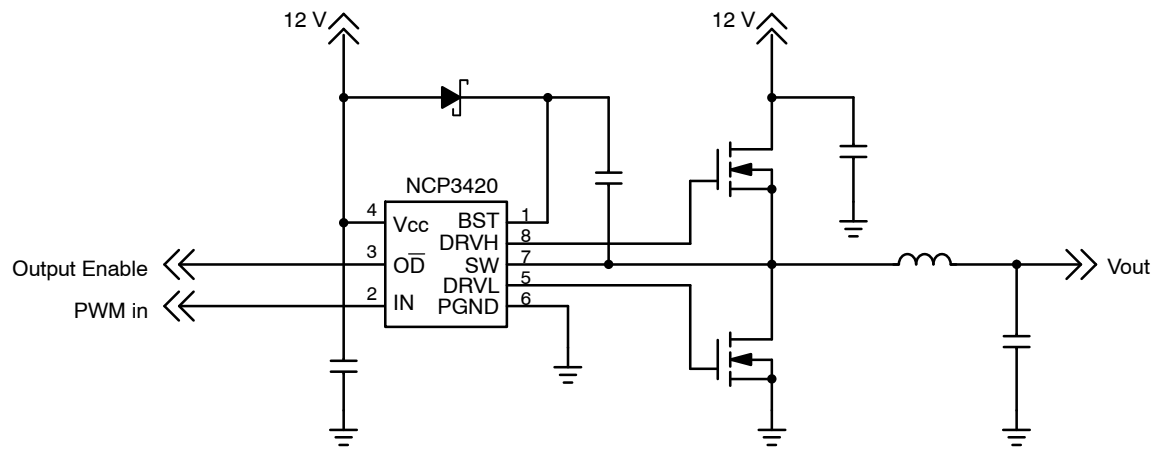
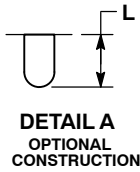
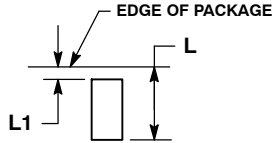
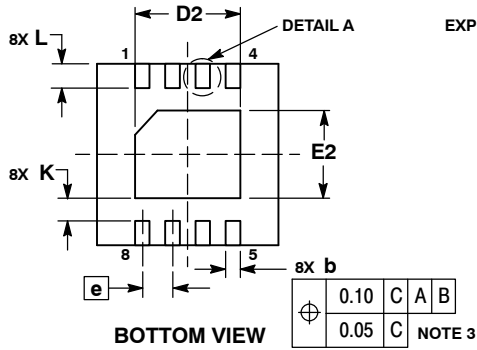
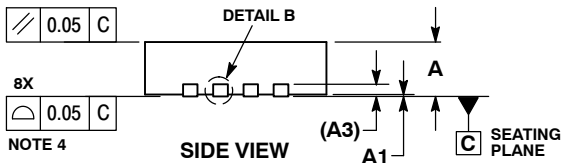
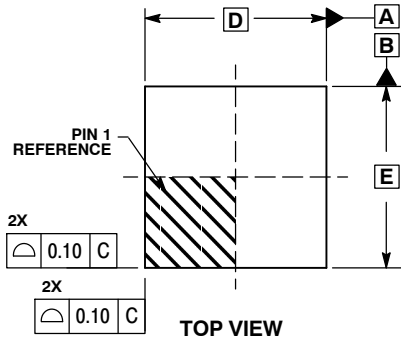


Figure 4. NCP3420 Example Circuit

NCP3420

PACKAGE DIMENSIONS

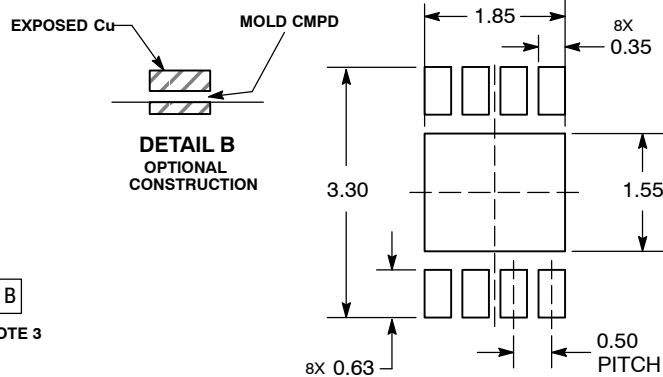
DFN8 3x3, 0.5P
CASE 506BJ-01
ISSUE O



- NOTES:
1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL.
 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.18	0.30
D	3.00	BSC
D2	1.64	1.84
E	3.00	BSC
E2	1.35	1.55
e	0.50	BSC
K	0.20	---
L	0.30	0.50
L1	0.00	0.03

SOLDERMASK DEFINED MOUNTING FOOTPRINT



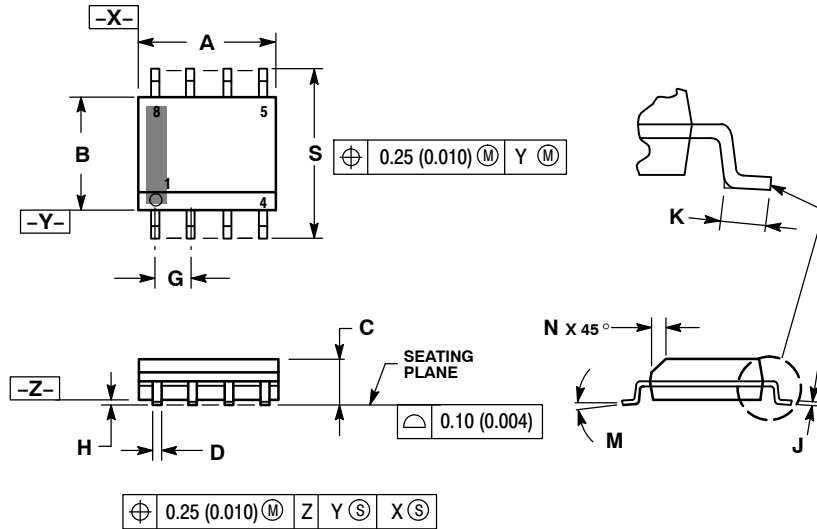
DIMENSION: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCP3420

PACKAGE DIMENSIONS

SOIC-8 D SUFFIX CASE 751-07 ISSUE AJ

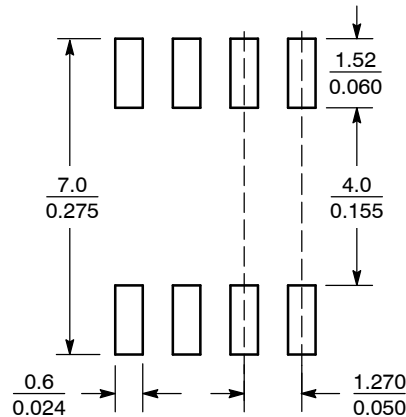


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



SCALE 6:1 (mm/inches)

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

Japan Customer Focus Center
Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local
Sales Representative

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru

www.lifeelectronics.ru